

# **YC1058**

**Bluetooth 4.2 BR + BLE + 2.4GHz-Proprietary** 

**Datasheet** 

Yichip Microelectronics ©2019

# **Revision History**

| Version     | Date       | Author | Description                       |
|-------------|------------|--------|-----------------------------------|
| preliminary | 2019-04-01 | L.D    | Initial version                   |
| V1.1        | 2019-04-09 | L.D    | Modified Pin Function Description |
| V1.2        | 2019-04-19 | L.D    | Update Schematic                  |
|             |            |        |                                   |
|             |            |        |                                   |
|             |            |        |                                   |
|             |            |        |                                   |
|             |            |        |                                   |
|             |            |        |                                   |
|             |            |        |                                   |
|             |            |        |                                   |

#### **General Description**

The YC1058 is a very low power, high performance and highly integrated Bluetooth 4.2 BR + BLE + 2.4G Proprietary triple-mode solution, designed for operation over the 2400MHz to 2483.5Mhz ISM frequency band.

YC1058 is manufactured using advanced 55nm CMOS low leakage process, which offers highest integration, lowest power consumption, lowest leakage current and reduced BOM cost while simplifying the overall system design. Rich peripherals including an 8 channel general purpose ADC, power-on-reset (POR), Arithmetic Accelerators, 3axis Q-decoder, ISO7816, UART/SPI/I2C and up to 23 GPIOs, which further reduce overall system cost and size.

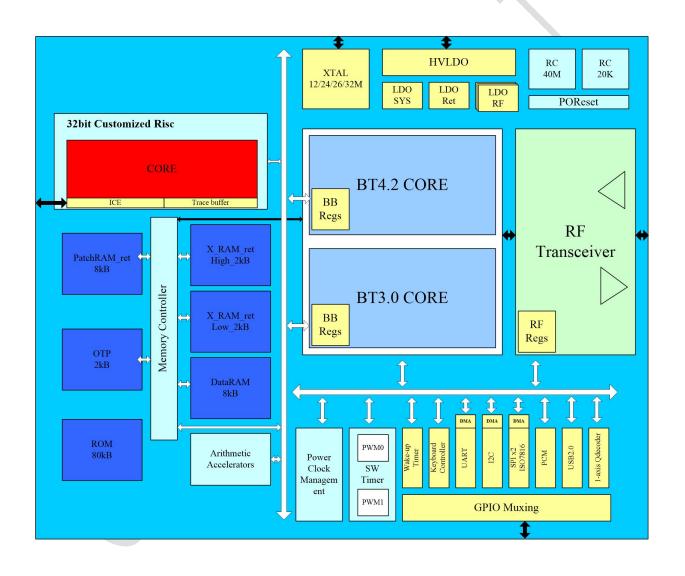
YC1058 operates with a power supply range from 1.8 to 5.5V and has very low power consumption in both Tx and Rx modes, enabling long lifetimes in battery-operated systems while maintaining excellent RF performance. The device can enter an ultra low power sleep mode in which the registers and retention memory content are retained while low power Oscillator and sleep timer is ON.

#### **Key Features**

- Bluetooth4.2BR+BLE+2.4GHz-Proprietary triple-mode RF SOC
- Very Low Power Consumption
  - 10nA shut down mode (external interrupts)
  - 900nA sleep mode ( 32kHz RC OSC, sleep timer and register ON)
  - 2uA retention mode (32kHz RC OSC, sleep timer, 2k retention memory and register ON)
  - Rx peak current @3V (ideal DCDC)
    - 6.75mA in BLE/2.4G mode
    - 7.25mA in in 3.0 mode
  - Tx peak current @3V (-2dBm, ideal DCDC)
    - 16.5mA in BLE/2.4G mode
    - 17mA in in 3.0 mode
  - Rx peak current w/o DCDC
    - 16mA in BLE/2.4G mode
    - 17mA in 3.0 mode
  - Tx peak current w/o DCDC @ -2dBm
    - 22mA in BLE/2.4G mode
    - 23mA in 3.0 mode
  - <25uA avg, 500ms sniff hold connection
- 2.4GHz Transceiver
  - Single-end RFIO
  - -93dBm in BLE mode
  - support 250kbps, 1Mbps data rates
  - Tx Power upto +6dBm

- Oscillators
  - 16M/24M/32M XTAL supported (default 24M)
  - 50M RC oscillator
  - Low Jitter 32K RC oscillator
- Single Core Digital Architecture
  - 32bit-Risc Core for link management
    - 80kB code ROM
    - 8kB code RAM
    - All RAMs can be set to retention mode
- Arithmetic Accelerators [Accuracy: (sign, 15b.16b)]
  - multi/div/sqrt
- Analog Peripherals
  - 8 channel ADC with 10 bit accuracy/3Msps
- Digital Peripherals
  - Two-wire Master (I2C compatible), upto 400kbps; UART(RTS/CTS) with HCI-H5 protocol, upto 3.25Mbps; SPI Master, upto 24Mbps
  - ISO7816
  - AES128 HW encryption
  - LED drive capability
  - PWM
  - 1 axis Q-decoder

# **Block Diagram**



# **Electrical Specifications**

| Name        | Parameter (Condition)   | Min     | Тур  | Max     | Unit         | Com<br>ment      |
|-------------|---|---------|------|---------|--------------|------------------|
| Power Sup   | plies   |         |      |         |              |                  |
| HVIN        | Voltage Input, typically 1uF decouple cap   | 3.1     | 4.2  | 5.5     | V            |                  |
| HVOUT       | Voltage Output, typically 1uF decouple cap, maximum 50mA load capability  | 2.75    | 2.85 | 2.95    | V            | (1)              |
| IQ_HV       | Quiescent Current of high voltage LDO   |         | 750  |         | nA           |                  |
| VIN         | Voltage Input, typically 1uF decouple cap   | 1.5     |      | 3.6     | V            |                  |
| VINPA       | Voltage Input, typically 5pF decouple cap   | 1.5     |      | 3.6     | V            | (2)              |
| VIO         | Voltage Input   | 1.7     |      | 3.6     | V            | (3)              |
| DVDD        | Voltage Output, typically 1uF decouple cap  | 1.1     | 1.2  | 1.3     | V            |                  |
| VDDLPM      | Voltage Output, typically 100nF decouple cap  | 1.1     | 1.2  | 1.3     | V            |                  |
| Temperatu   | re  |         | A    |         | P            |                  |
| TEMP        | Temperature   | -20     |      | +85     | $^{\circ}$ C |                  |
| Digital Inp | ut Pin  |         |      |         |              |                  |
| VIH         | High Level  | VIO-0.3 |      | VIO+0.3 | V            |                  |
| VIL         | Low Level   | VSS     |      | VSS+0.3 | V            |                  |
| Digital Onp | out Pin   |         |      |         |              |                  |
| VOH         | High Level  | VIO-0.3 |      | VIO+0.3 | V            | (4)              |
| VOL         | Low Level   | VSS     |      | VSS+0.3 | V            | (4)              |
| Current Co  | onsumption  |         |      |         |              |                  |
| IVDD        | Shut down mode, can only be waked up by wake-up pin.  |         | 10   |         | nA           |                  |
| IVDD        | Retention mode (LPO, no retention RAM, POR, sleep timer, I/O interrupts ON), can be waked up by sleep timer & any GPIO  |         | 0.70 |         | uA           | ( <del>-</del> ) |
| IVDD        | Retention mode (LPO, 2kB retention RAM, POR, sleep timer, I/O interrupts ON), can be waked up by sleep timer & any GPIO |         | 1.25 |         | uA           | (5)              |
| IVDD        | RX mode, BLE & 2.4G mode, 100% ON (with ideal DCDC @3V)   |         | 6.75 |         | mA           | (6)              |
| IVDD        | TX mode, BLE & 2.4G mode, 100% ON (with ideal DCDC @3V)   |         | 16   |         | mA           | (7)              |
| IVDD        | Average Current, 500ms sniff, hold connection   |         |      | 25      | uA           |                  |
| Normal RF   | Condition   |         |      |         |              |                  |
| FOP         | Operating Frequency   | 2400    |      | 2480    | MHz          |                  |
| FXTAL       | Crystal Frequency   | 12      | 24   | 32      |              | (8)              |
| Transmitte  | r Characteristics   |         |      |         |              |                  |
| PRF         | RF output power   | -20     | 0    | 6       | dBm          |                  |
| CD          | Carrier Drift Rate  |         | 5    |         | kHz/50us     |                  |
| PRF1        | Out of band emission 2 MHz (GFSK)   |         | -40  |         | dBm          |                  |



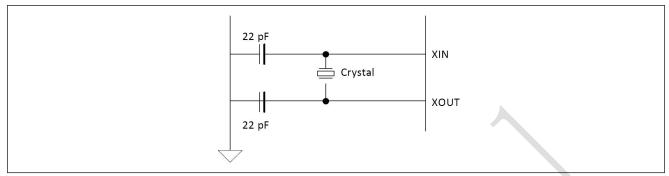
| DD E2      | O + Cl 1 · · · · · · · · · · · · · · · · · ·  |   | 40  |     | 1D  |  |  |
|------------|---|---|-----|-----|-----|--|--|
| PRF2       | Out of band emission 3 MHz (GFSK)             |   | -48 |     | dBm |  |  |
| BW         | 20dB bandwidth 0.9                            |   |     |     | MHz |  |  |
|            | Modulation Accuracy, RMS DEVM ( π /4          |   | 7   | 20  | %   |  |  |
|            | DQPSK)  |   |     |     |     |  |  |
|            | Modulation Accuracy, RMS DEVM (8PSK)          |   | 7   | 13  | %   |  |  |
|            | Modulation Accuracy, 99% DEVM ( π /4          |   | 14  | 30  | %   |  |  |
| EVM        | DQPSK)  |   |     |     |     |  |  |
|            | Modulation Accuracy, 99% DEVM (8PSK)          |   | 14  | 20  | %   |  |  |
|            | Modulation Accuracy, Peak DEVM ( π /4         |   | 18  | 35  | %   |  |  |
|            | DQPSK & 8PSK)                                 |   | 10  | 33  |     |  |  |
|            | Modulation Accuracy, Peak DEVM (8PSK)         |   | 18  | 25  | %   |  |  |
| PRF1       | Out of band emission 2 MHz ( $\pi$ /4 DQPSK & |   | -30 | -20 |     |  |  |
| 1 KI 1     | 8PSK)   |   | -30 | -20 |     |  |  |
| PRF2       | Out of band emission 3 MHz ( $\pi$ /4 DQPSK & |   | -42 | -40 |     |  |  |
| PKF2       | 8PSK)   |   | -42 | -40 | -40 |  |  |
| Receiver C | Characteristics                               |   |     |     |     |  |  |
|            | BT4.0 (BLE)                                   |   |     |     |     |  |  |
| SEN        | High Gain mode, Sensitivity @0.1%             |   | -93 |     | dBm |  |  |
| SEN        | Standard Gain mode, Sensitivity @0.1%         |   | -87 |     | dBm |  |  |
| MaxIn      | Maximum Input Power                           |   | 0   |     | dBm |  |  |
| C/ICO      | Co-channel C/I, Basic Rate, GFSK              |   | 7   |     | dB  |  |  |
| C/I1ST     | ACS C/I 1MHz, Basic Rate, GFSK                |   | 5.5 | 7   | dB  |  |  |
| C/I2ND     | ACS C/I 2MHz, Basic Rate, GFSK                |   | -36 | -34 | dB  |  |  |
| C/I3RD     | ACS C/I 3MHz, Basic Rate, GFSK                |   | -43 |     | dB  |  |  |
| C/I1STI    | ACS C/I Image channel, Basic Rate, GFSK       |   | -34 |     | dB  |  |  |
| C/IO) ID I | C/I 1 MHz adjacent to image channel, Basic    |   | 20  |     | 1D  |  |  |
| C/I2NDI    | Rate, GFSK                                    |   | -28 |     | dB  |  |  |
|            | BT3.0 (BR)                                    | l |     | ı   | 1   |  |  |
| SEN        | Basic Rate, GFSK, BER<0.1%, Dirty Tx on       |   | -90 |     | dBm |  |  |
| MaxIn      | Maximum Input Power                           |   | 0   |     | dBm |  |  |

- (1) HVIN & HVOUT are input & output of a high voltage LDO which is integrated in YC1058, input voltage range from 3.1~5.5V, and maximum load capability upto 50mA. Typically used in Li BAT (3.2~4.2V) or USB Power(4.5~5.5V) applications. If input voltage is lower than 3.6V, HVIN & HVOUT should be left unconnected and YC1058 should be powered by VIN/VINLPM/VINPA directly.
- (2) If RF output power should be larger than -4dBm, VINPA should be larger than 2.5V.
- (3) VIO should always be powered ON in all working cycles.
- (4) Drive capability of GPIO[6:7] & GPIO[18:22] is up to 30mA, other GPIO's drive capability is 10mA
- (5) By default, 2kB retention memory is ON in retention mode. Up to 4kB retentionable X memory available at the cost of extra 600nA retention mode current. Result based on standard gain mode
- (6) Result based on -2dBm Pout
- (7) 12M, 16M, 24M, 26M, 32M crystal supported, 24M by default

### **Crystal Oscilator**



The crystal oscillator requires a crystal with an accuracy of ±30 ppm as defined by the Bluetooth specification. Two external load capacitors in the range of 5 pF to 30 pF are required to work with the crystal oscillator. The selection of the load capacitors is crystal dependent. The recommended crystal specification shows below.



Recommended Oscillator Configuration — 20 pF Load Crystal

| Name                          | Parameter (Condition) | Min | Тур         | Max | Unit   | Comment |
|-------------------------------|-----------------------|-----|-------------|-----|--------|---------|
| Frequency                     |                       |     | 24          |     | MHz    |         |
| Oscillation mode              |                       |     | Fundamental |     |        |         |
| Frequency tolerance           | @25°C                 |     | ±10         | ±30 | ppm    |         |
| Tolerance stability over temp | @0°C to +70°C         |     | ±10         | ±30 | ppm    |         |
| Load capacitance              |                       |     | 20          |     | pF     |         |
| Operating temperature range   |                       | -20 |             | +70 | degree |         |
| Drive Level                   |                       |     | 100         |     | uW     |         |

## **Power consumption**

| W/O DC-DC Parameter |  | Average Current | Unit |
|---------------------|--|-----------------|------|
| Sleep               | 1  | 700             | nA   |
| Sniff               | 500ms interval                               | 21.99           | uA   |
| Discoverable        | ADV interval: 640ms<br>Scan interval: 1280ms | 138.66          | uA   |
|                     | Scan window: 11.25ms                         |                 |      |

| With DC-DC   | Parameter             | Average Current | Unit |
|--------------|-----------------------|-----------------|------|
| Sleep        | /                     | 700             | nA   |
| Sniff        | Sniff Interval:500ms  | 17.92           | uA   |
|              | ADV interval: 640ms   |                 |      |
| Discoverable | Scan interval: 1280ms | 89.5            | uA   |
|              | Scan window: 11.25ms  |                 |      |



# **Bluetooth Security**

- 1. Pairing
  - Pin Code
- 2. Security Simple Pairing
  - Just Work(No input)
  - Keyboard
  - DisplayYesNo

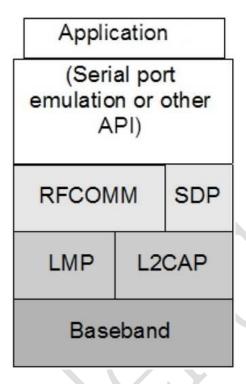
#### **MFi**

Support Apple's MFi authentication and iAP1/iAP2 protocols.

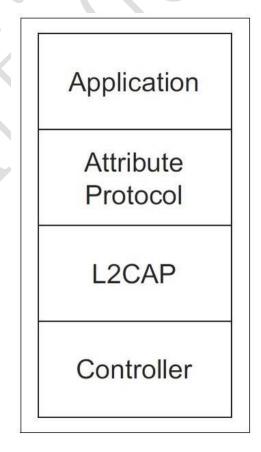


#### **Bluetooth Stack**

#### 1. Serial Port Profile

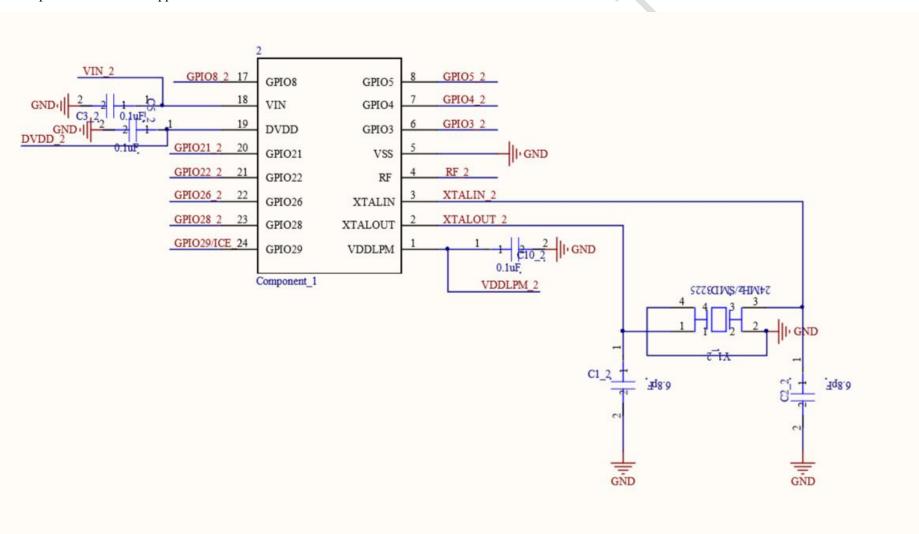


#### 2. Generic Attribute Profile



# **Application Schematic**

1. Transparent transmission application





# **Package Information**

| VDDLPM  | 1 |                 | 16 | GPIO29/ICE |
|---------|---|-----------------|----|------------|
| XTALOUT | 2 |                 | 15 | GPIO28     |
| XTALIN  | 3 | <b>.</b>        | 14 | GPIO26     |
| RF      | 4 | C1058-<br>OP16L | 13 | GPIO22     |
| VSS     | 5 | C1<br>(OP       | 12 | GPIO21     |
| GPIO3   | 6 |                 | 11 | DVDD       |
| GPIO4   | 7 |                 | 10 | VIN        |
| GPIO5   | 8 |                 | 9  | GPIO8      |
|         |   |                 |    |            |



| SOP | Pin Name     | Туре    | Function Description  |  |
|-----|--------------|---------|---|--|
| 16  |              |         |   |  |
| 1   | VDDLPM       | Power_O | internal LDO output, 1.2V. Need an external bypass cap here 100nF |  |
| 2   | XTALOUT      | Ana_O   | XTAL port   |  |
| 3   | XTALIN       | Ana_I   | XTAL port, or external CLK in                                     |  |
| 4   | RF           | RF Port |   |  |
| 5   | VSS          | Power_O | GND   |  |
| 6   | GPIO[3]      | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |
| 7   | GPIO[4]      | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |
| 8   | GPIO[5]      | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |
| 9   | VIN          | Power_O | Voltage Input,3.3V typically 0.1uF decouple cap                   |  |
| 10  | DVDD         | Power_O | internal LDO output, 1.2V. Need an external bypass cap here 0.1uF |  |
| 11  | GPIO[8]      | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |
| 12  | GPIO[21]     | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |
| 13  | GPIO[22]     | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |
| 14  | GPIO[26]     | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |
| 15  | GPIO[28]     | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |
| 16  | GPIO[29]\ICE | Dig_IO  | pls check "sheet: GPIO_Muxing"                                    |  |

Note: Most GPIOs are by default configured to input status after power-on reset, except for GPIO2 & GPIO24/25/26 which are in output status. If a GPIO is not used as well as it is not configured to output, it can be connected to GND. But GPIO2 & GPIO24/25/26 MUST NOT be connect to GND at any time.



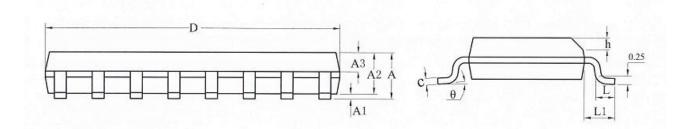
#### **GPIO Muxing Table**

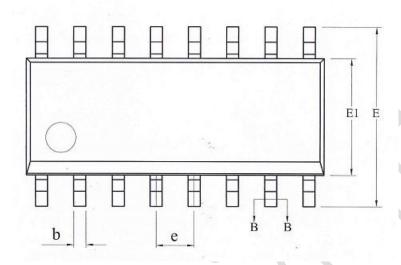
| GPIOs    | Function1 | Function2 | Function-Ana |
|----------|-----------|-----------|--------------|
| GPIO[3]  | UARTCTS   | PWM OUT4  | adc_channel1 |
| GPIO[4]  | PWM OUT0  |           | adc_channel2 |
| GPIO[5]  | PWM OUT1  |           | adc_channel3 |
| GPIO[8]  | PWM OUT5  |           | wakeup       |
| GPIO[21] | PWM OUT1  |           |              |
| GPIO[22] | PWM OUT2  |           |              |
| GPIO[26] | SPIMOSI   | TWSDAT    |              |
| GPIO[28] | PWM OUT3  | ZB        |              |
| GPIO[29] |           |           |              |

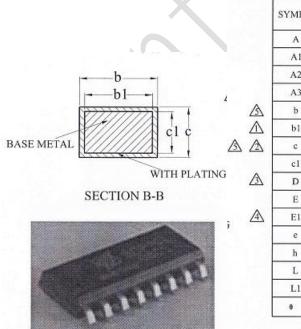
Note: Drive capability of GPIO[3:5] & GPIO[27:29] is up to 100mA,GPIO8 internal pulldown also can drive 100mA, other GPIO's drive capability is 10mA.



# Package Physical Dimension (SOP\_16 16L)







| SYMBOL | MI      | LLIME  | TER   |  |
|--------|---------|--------|-------|--|
| SYMBOL | MIN     | NOM    | MAX   |  |
| A      | _       | _      | 1.75  |  |
| A1     | 0.10    | _      | 0.225 |  |
| A2     | 1.30    | 1.40   | 1.50  |  |
| A3     | 0.60    | 0.65   | 0.70  |  |
| b      | 0.39    | _      | 0.47  |  |
| ь1     | 0.38    | 0.41   | 0.44  |  |
| c      | 0.20    | _      | 0.24  |  |
| cl     | 0.19    | 0.20   | 0.21  |  |
| D      | 9.80    | 9.90   | 10.00 |  |
| Е      | 5.80    | 6.00   | 6.20  |  |
| El     | 3.80    | 3.90   | 4.00  |  |
| e      |         | .27BSC |       |  |
| h      | 0.25    | =      | 0.50  |  |
| L      | 0.50    | -      | 0.80  |  |
| L1     | 1.05REF |        |       |  |
| θ      | 0       | _      | 8*    |  |